

20 V, 2 A PNP low VCEsat transistor

22 June 2022

# 1. General description

PNP low V<sub>CEsat</sub> transistor in a SOT23 small Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- + High collector current capability:  $I_C$  and  $I_{CM}$
- Higher efficiency leading to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-2	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-3	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -2 A; $I_B$ = -200 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	113	mΩ

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	E	emitter		J
3	С	collector		В
				E
			1 2 SOT23	



## 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS5220T-Q	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	<u>SOT23</u>			

## 7. Marking

Table 4. Marking codes						
Type number	Marking code[1]					
PBSS5220T-Q	%3F					

[1] % = placeholder for manufacturing site code

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-20	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-20	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-3	А
I <sub>B</sub>	base current			-	-300	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

# 9. Thermal characteristics

## Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	417	K/W
	junction to ambient		[2]	-	-	260	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

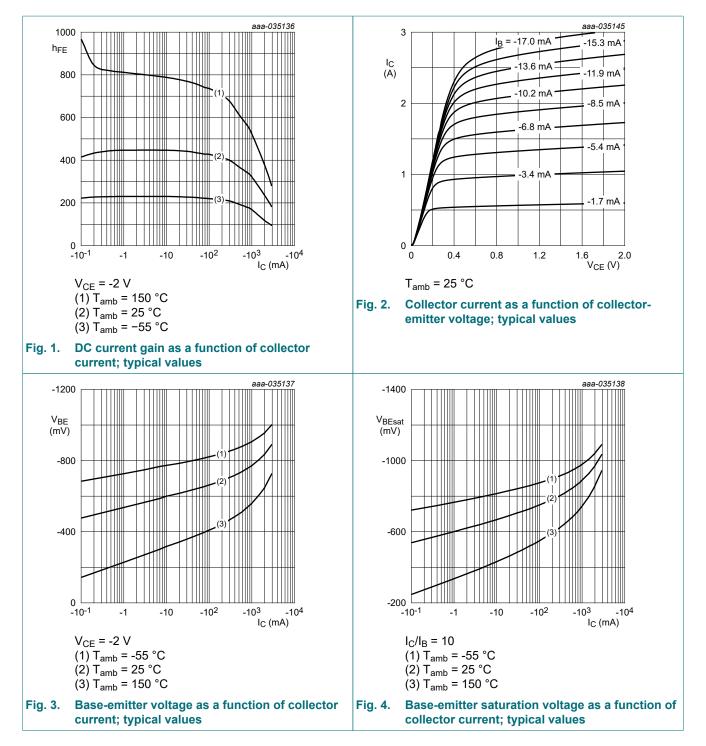
PBSS5220T-Q

# **10. Characteristics**

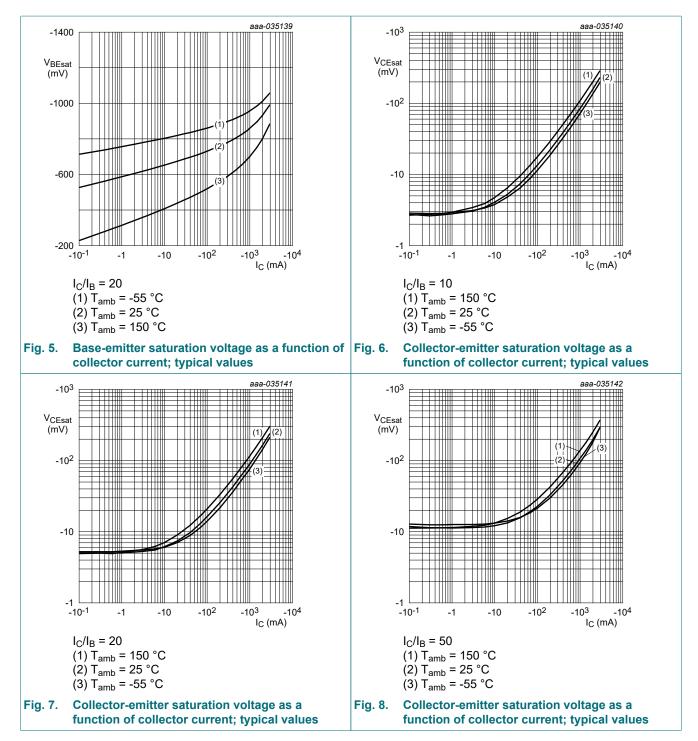
Parameter	Conditions	N	lin	Тур	Max	Unit
collector-base cut-off	V <sub>CB</sub> = -20 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-		-	-100	nA
current	V <sub>CB</sub> = -20 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-		-	-50	μA
emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C}$	-		-	-100	nA
DC current gain	$V_{CE}$ = -2 V; I <sub>C</sub> = -100 mA; T <sub>amb</sub> = 25 °C	2	25	-	-	
	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA; T <sub>amb</sub> = 25 °C	2	25	-	-	
	$V_{CE}$ = -2 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T <sub>amb</sub> = 25 °C	2	00	-	-	
	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -2 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	1	50	-	-	
collector-emitter saturation voltage	$I_{C}$ = -500 mA; $I_{B}$ = -50 mA; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C; pulsed	-		-	-80	mV
	$I_C$ = -1 A; $I_B$ = -50 mA; $t_p \le 300 \ \mu$ s; δ ≤ 0.02; $T_{amb}$ = 25 °C; pulsed	-		-	-150	mV
	$I_{C}$ = -2 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-		-	-250	mV
	$I_{C}$ = -2 A; $I_{B}$ = -200 mA; pulsed; $t_{p} \le$	-		-	-225	mV
collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-		-	113	mΩ
base-emitter saturation voltage	$I_{C}$ = -2 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-		-	-1.1	V
base-emitter turn-on voltage	$V_{CE}$ = -2 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T <sub>amb</sub> = 25 °C		1.2	-	-	V
transition frequency	$V_{CE}$ = -5 V; I <sub>C</sub> = -100 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	1	00	-	-	MHz
collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-		-	50	pF
	collector-base cut-off currentemitter-base cut-off currentDC current gainDC current gaincollector-emitter saturation voltagecollector-emitter saturation resistancebase-emitter saturation voltagebase-emitter turn-on voltagetransition frequency	$\begin{array}{ c c c c c } \hline \text{collector-base cut-off}\\ \hline \text{current} & \forall_{CB} = -20 \ \forall; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CB} = -20 \ \forall; \ I_E = 0 \ A; \ T_{j} = 150 \ ^{\circ}\text{C} \\ \hline \forall_{CB} = -20 \ \forall; \ I_E = 0 \ A; \ T_{j} = 150 \ ^{\circ}\text{C} \\ \hline \forall_{CB} = -20 \ \forall; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CB} = -2 \ \forall; \ I_C = -100 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -200 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -200 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -200 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -200 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -200 \ \text{mA}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -2 \ \forall; \ I_C = -2 \ \text{A}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \forall_{CE} = -200 \ \text{mA}; \ T_{B} = -50 \ \text{mA}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline I_C = -2 \ A; \ I_B = -50 \ \text{mA}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline I_C = -2 \ A; \ I_B = -50 \ \text{mA}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline I_C = -2 \ A; \ I_B = -100 \ \text{mA}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline I_C = -2 \ A; \ I_B = -100 \ \text{mA}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline I_C = -2 \ A; \ I_B = -100 \ \text{mA}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline base-emitter \ \text{saturation} \ \text{resistance} \\ \hline base-emitter \ \text{saturation} \ \text{resistance} \\ \hline \hline v_{CE} = -2 \ \forall; \ I_C = -1 \ \text{A}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline base-emitter \ \text{turn-on} \ \text{voltage} \ \hline \forall_{CE} = -2 \ \forall; \ I_C = -100 \ \text{mA}; \ \text{pulsed}; \ t_p \le 300 \ \text{µs}; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline \text{transition \ frequency}  \forall_{CE} = -5 \ \forall; \ I_C = -100 \ \text{mA}; \ f = 100 \ \text{mHz}; \\ T_{amb} = 25 \ ^{\circ}\text{C} \\ \hline \hline \hline \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{ c c c c c c } \hline \mbox{collector-base cut-off} \\ \mbox{current} & V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - \\ \hline V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_j = 150 \ ^{\circ}C & - \\ \hline \hline V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_j = 150 \ ^{\circ}C & - \\ \hline \hline V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - \\ \hline \hline \mbox{current} & V_{EB} = -5 \ V; \ I_C = -100 \ mA; \ T_{amb} = 25 \ ^{\circ}C & 225 \\ \hline \hline V_{CE} = -2 \ V; \ I_C = -1 \ A; \ pulsed; \ t_p \le & 200 \\ \hline \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$ \begin{array}{ c c c c c c c } \hline collector-base cut-off current & V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - & - & - & - & - & - & - & - & - & $	$ \begin{array}{ c c c c c c c } \hline \mbox{current} & V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - & - & -100 \\ \hline V_{CB} = -20 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - & - & -50 \\ \hline \mbox{emitter-base cut-off current} & V_{EB} = -5 \ V; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C & - & - & -& -100 \\ \hline \mbox{ourrent} & V_{CE} = -2 \ V; \ I_C = -100 \ mA; \ T_{amb} = 25 \ ^{\circ}C & 225 & - & - \\ \hline \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$

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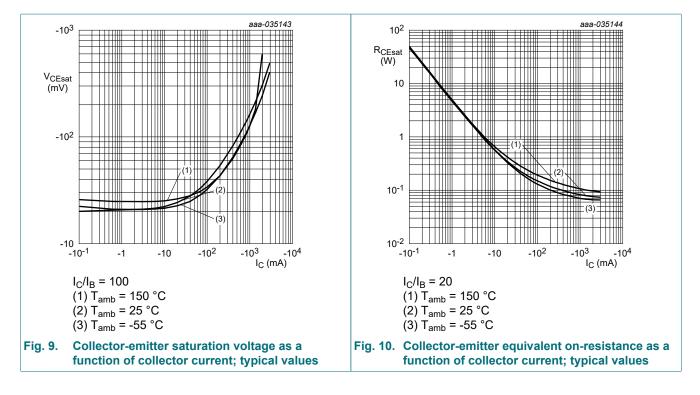
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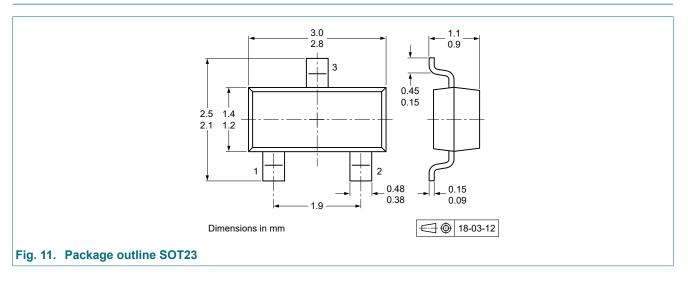


## **11. Test information**

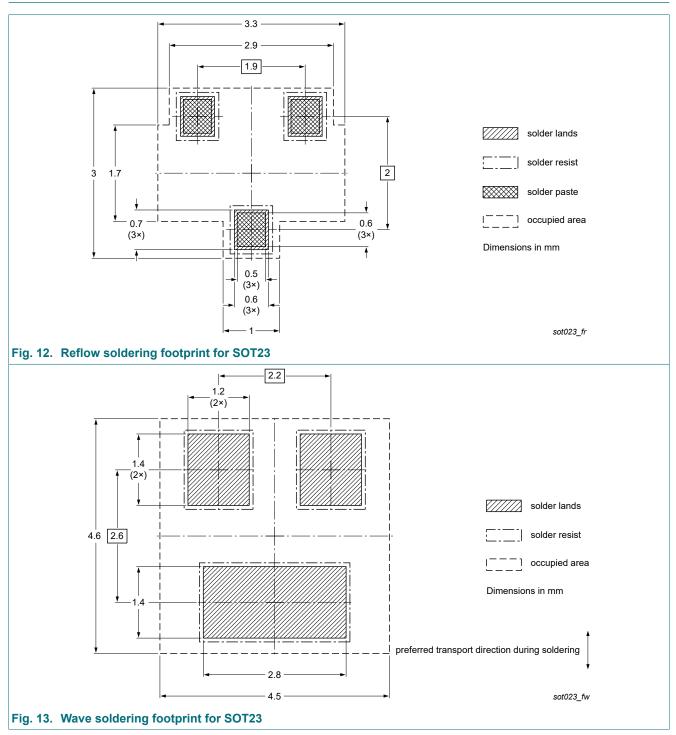
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline



# 13. Soldering



# 14. Revision history

Table 8. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBSS5220T-Q v.2	20220622	Product data sheet	-	PBSS5220T-Q v.1				
Modifications:	Characteristics: Figu	Characteristics: Figures 1 - 10 added						
PBSS5220T-Q v.1	20220524	Product data sheet	-	-				

PBSS5220T-Q

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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